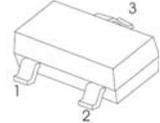


SOT-23 Plastic-Encapsulate NMOSFETS

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
50V	3.5Ω@10V	220mA
	6Ω@4.5V	

SOT-23

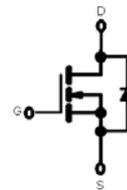
1. GATE
2. SOURCE
3. DRAIN


FEATURE

- High density cell design for extremely low $R_{DS(on)}$
- Rugged and Reliable

APPLICATION

- Direct Logic-Level Interface: TTL/CMOS
- Drivers: Relays, Solenoids, Lamps, Hammers; Display, Memories, Transistors, etc.
- Battery Operated Systems
- Solid-State Relays

Equivalent Circuit

Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	50	V
Continuous Gate-Source Voltage	V_{GSS}	±20	
Continuous Drain Current	I_D	0.22	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	$^\circ\text{C}/\text{W}$
Operating Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-55 ~ +150	

ELECTRICAL CHARACTERISTICS

$T_a=25\text{ }^\circ\text{C}$ unless otherwise specified

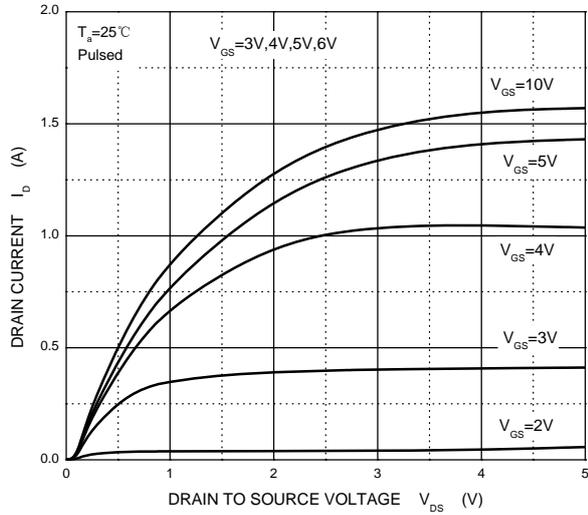
Parameter	Symbol	Test Condition	Min	Typ	Max	Units
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	50			V
Gate-body leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 20V$			± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 50V, V_{GS} = 0V$			0.5	μA
		$V_{DS} = 30V, V_{GS} = 0V$			100	nA
On characteristics						
Gate-threshold voltage (note 1)	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 1mA$	0.80		1.50	V
Static drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 0.22A$			3.50	Ω
		$V_{GS} = 4.5V, I_D = 0.22A$			6	
Forward transconductance (note 1)	g_{FS}	$V_{DS} = 10V, I_D = 0.22A$	0.12			S
Dynamic characteristics (note 2)						
Input capacitance	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V, f = 1MHz$		27		pF
Output capacitance	C_{oss}			13		
Reverse transfer capacitance	C_{rss}			6		
Switching characteristics						
Turn-on delay time (note 1,2)	$t_{d(on)}$	$V_{DD} = 30V, V_{DS} = 10V, I_D = 0.29A, R_{GEN} = 6\Omega$			5	ns
Rise time (note 1,2)	t_r				18	
Turn-off delay time (note 1,2)	$t_{d(off)}$				36	
Fall time (note 1,2)	t_f				14	
Drain-source body diode characteristics						
Body diode forward voltage (note 1)	V_{SD}	$I_S = 0.44A, V_{GS} = 0V$			1.4	V

Notes:

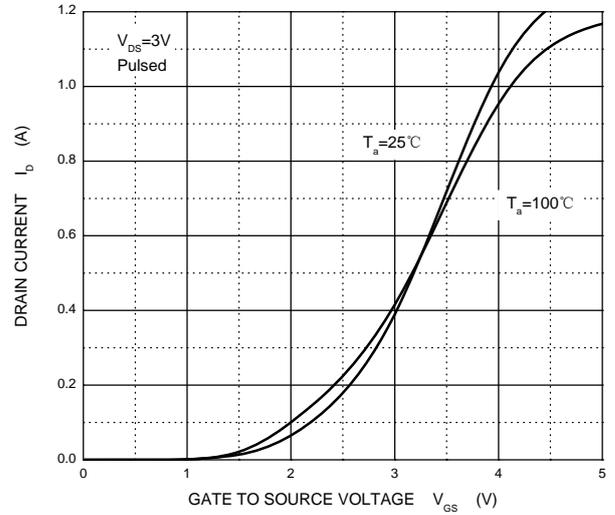
1. Pulse Test ; Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
2. These parameters have no way to verify.

Typical Characteristics

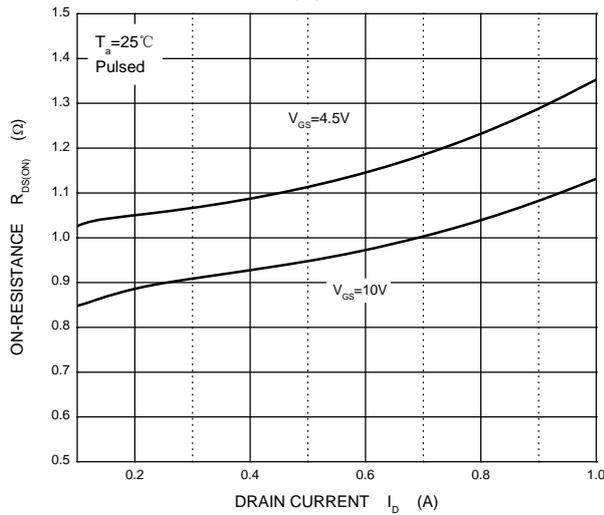
Output Characteristics



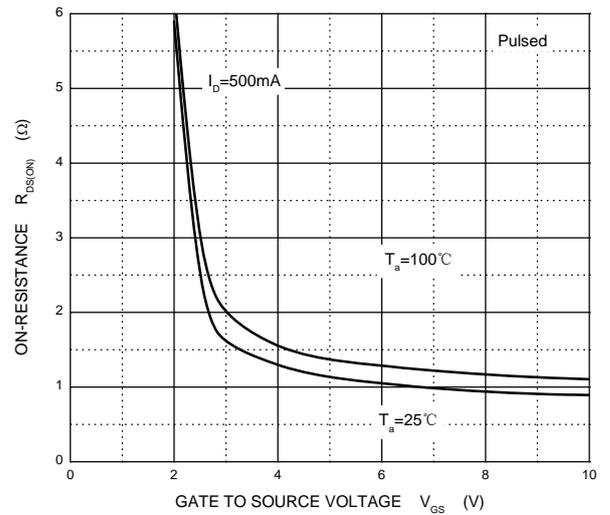
Transfer Characteristics



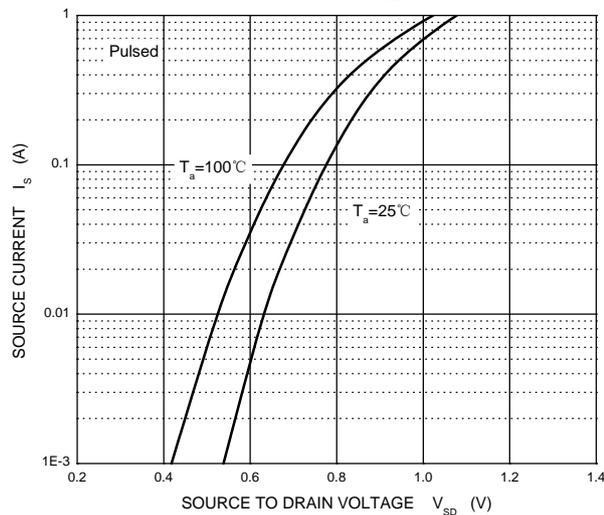
$R_{DS(ON)}$ — I_D



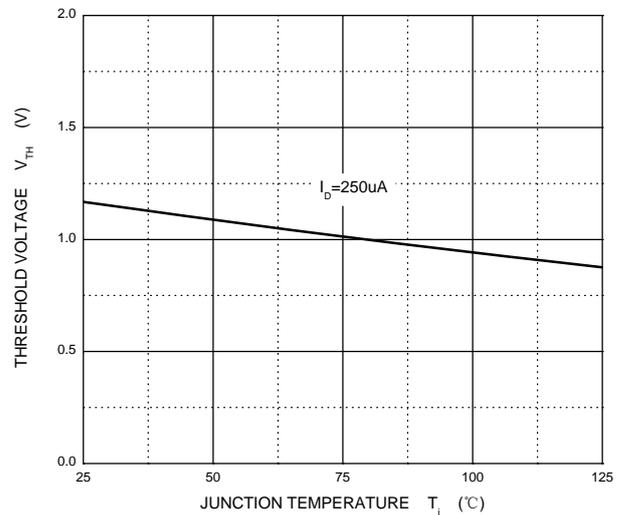
$R_{DS(ON)}$ — V_{GS}



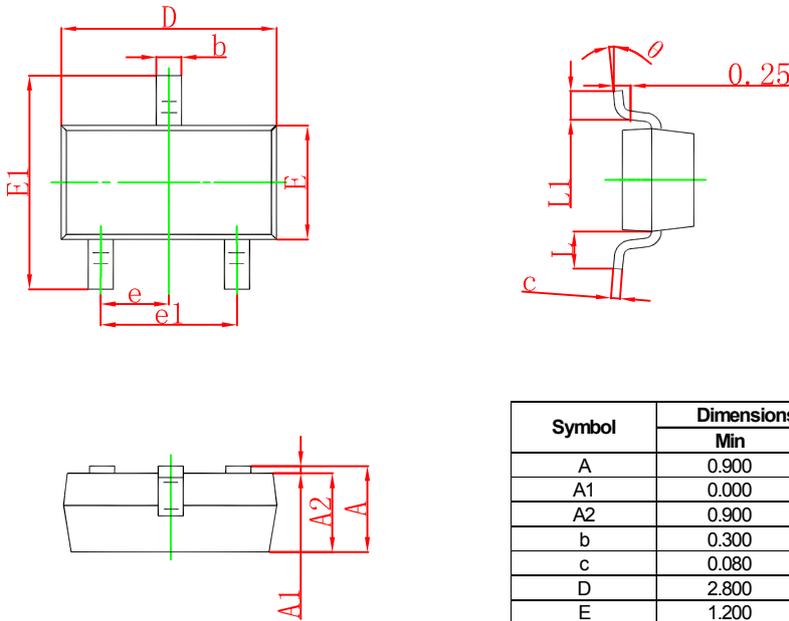
I_S — V_{SD}



Threshold Voltage

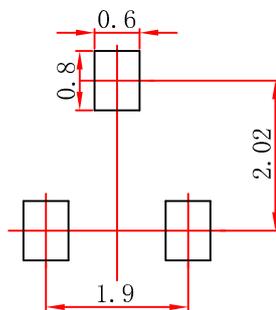


SOT-23 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP		0.037 TYP	
e1	1.800	2.000	0.071	0.079
L	0.550 REF		0.022 REF	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°

SOT-23 Suggested Pad Layout



- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: ± 0.05 mm.
 3. The pad layout is for reference purposes only.

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